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NMOS TRASISTOR

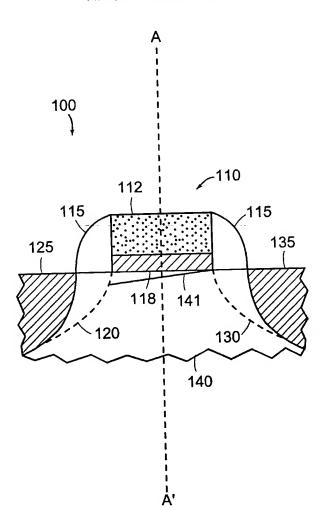
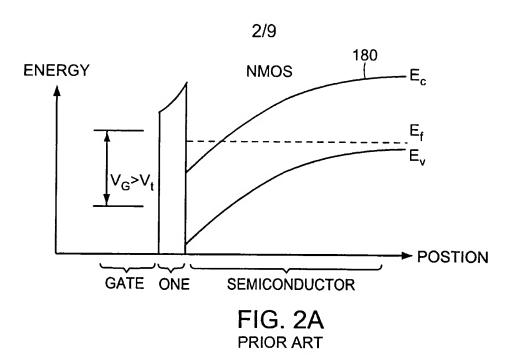
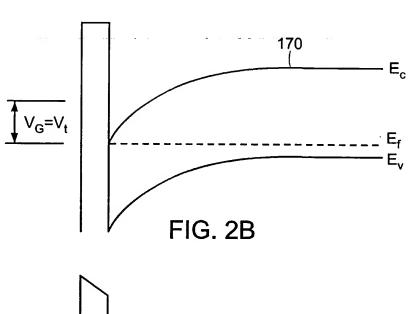
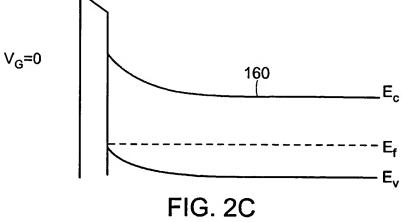


FIG. 1 PRIOR ART

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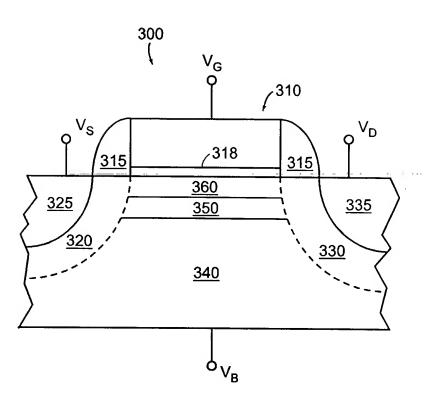


FIG. 3A

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N-CHANNEL

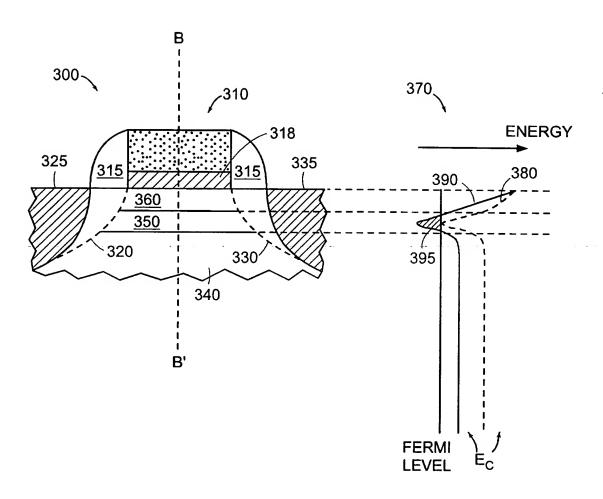


FIG. 3B

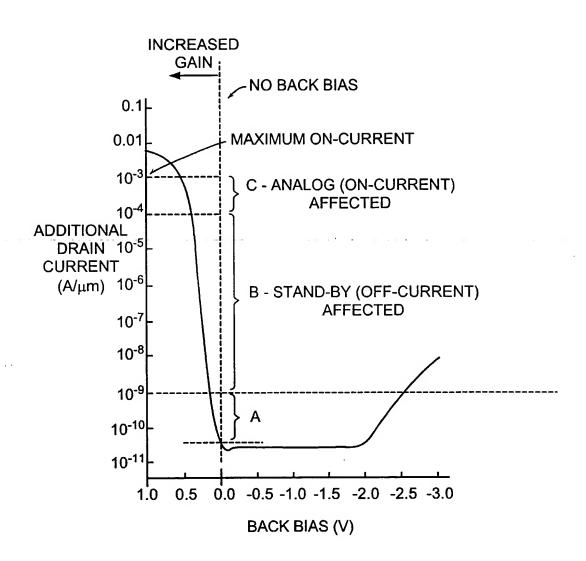


FIG. 3C

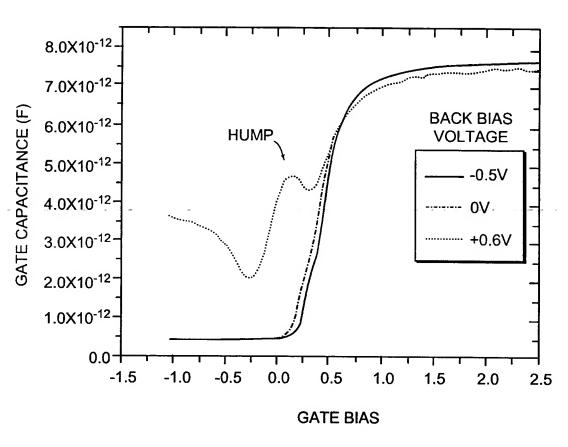


FIG. 4A

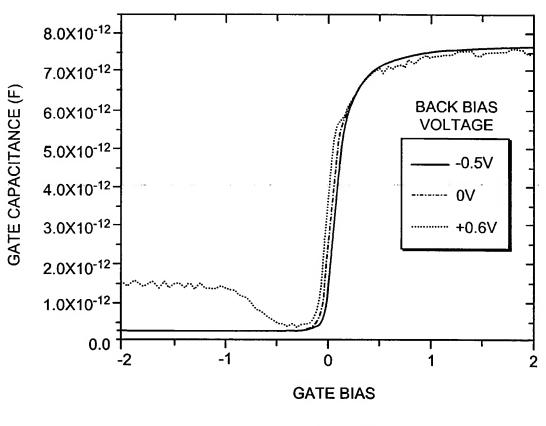


FIG. 4B

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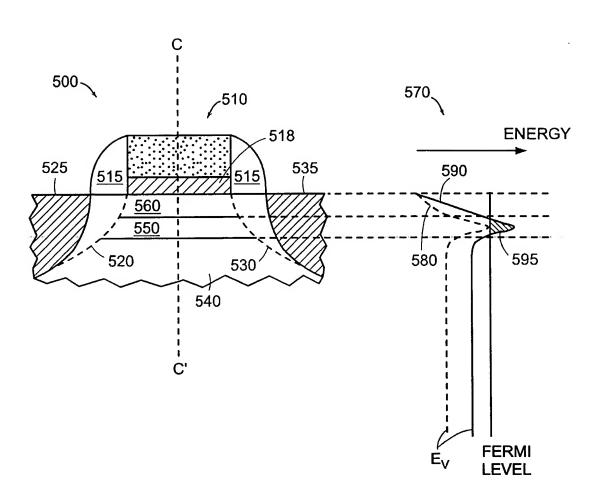
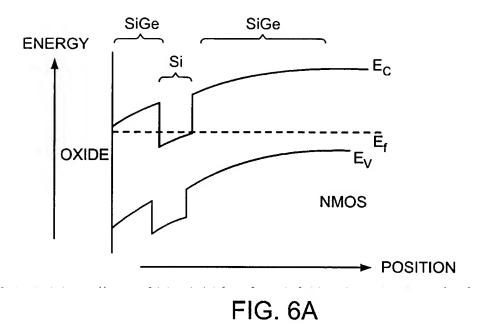


FIG. 5

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OXIDE SiGe SiGe PMOS E_C PMOS E_V FIG. 6B